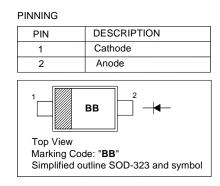
# SD188SBWS

# SILICON SCHOTTKY BARRIER DIODE

### Features

- Small surface mounting type
- $\bullet$  Ultra low  $V_{\text{F}}$
- High reliability



#### Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V <sub>RM</sub>	20	V
Reverse Voltage	V <sub>R</sub>	10	V
Mean Rectifying Current	Ι <sub>ο</sub>	200	mA
Peak Forward Surge Current	I <sub>FSM</sub>	0.5	А
Junction Temperature	Tj	125	°C
Storage Temperature Range	Ts	- 40 to + 125	°C

## Characteristics at T<sub>a</sub> = 25 °C

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 50 \text{ mA}$ at $I_F = 200 \text{ mA}$	V <sub>F</sub>	0.3 0.41	V
Reverse Current at V <sub>R</sub> = 10 V	I <sub>R</sub>	20	μA

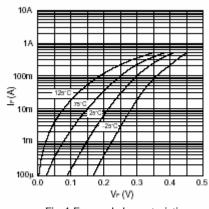
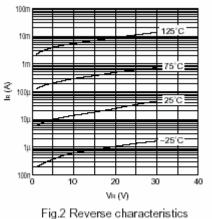


Fig.1 Forward characteristics



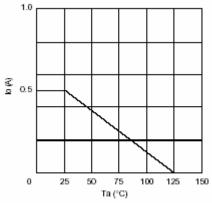


Fig.3 Derating curve



# SEMTECH ELECTRONICS LTD.

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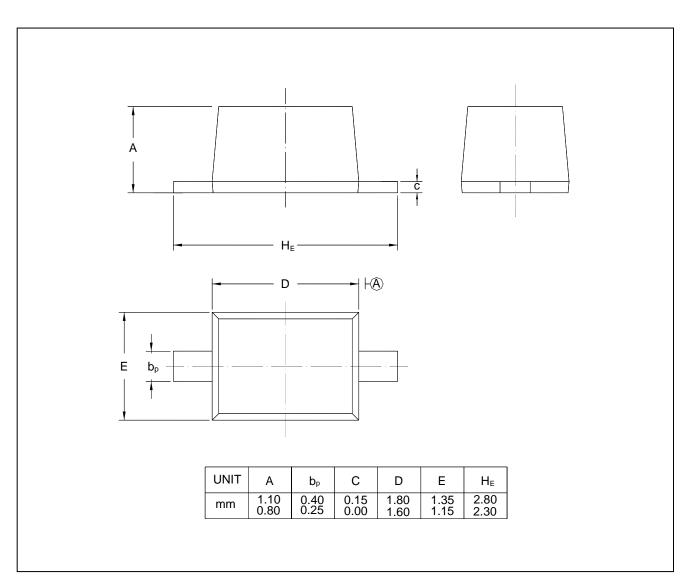


Dated : 01/09/2006

# PACKAGE OUTLINE

## Plastic surface mounted package; 2 leads

SOD-323





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